## NSN 5961-01-414-9169

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Inclosure Material:
Plastic
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-236ab
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage,
static, collector open
Terminal Type And Quantity:
3 bonding pad
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0